Diode Semiconductor Device - Page 1 of 1



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Inclosure	Material:
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Metal

**Overall Length:** 

0.185 inches

# Terminal Length:

0.500 inches

# **Overall Diameter:**

0.335 inches

#### **Function For Which Designed:**

Photodiode

### Mounting Method:

Terminal

### **Terminal Circle Diameter:**

0.210 inches

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

350.0 breakdown voltage, instantaneous

### **Current Rating Per Characteristic:**

5.00 microamperes repetitive peak forward current peak

# Capacitance Rating In Picofarads:

4.0

## Maximum Operating Tempurature Per Measurement Point:

60.0 degrees celsius ambient air

### **Test Data Document:**

82577-13043759 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

3 uninsulated wire lead

### Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

No

### Fiig:

A110a0